

INCHANGE SEMICONDUCTOR

iscN-Channel MOSFET Transistor

TK3A65DA, ITK3A65DA

• FEATURES

- Low drain-source on-resistance: RDs(ON) = 2.3Ω (typ.)
- Enhancement mode:

Vth = 2.4 to 4.4V (VDs = 10 V, ID=1.0mA)

- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

Switching Voltage Regulators

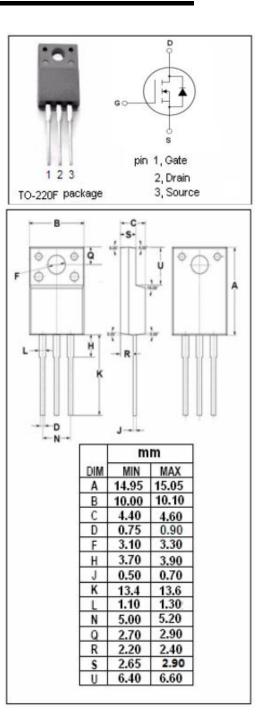
• ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

SYMBOL	PARAMETER	VALUE	UNIT				
V _{DSS}	Drain-Source Voltage	650	V				
V _{GS}	Gate-Source Voltage	±30	V				
ID	Drain Current-Continuous	2.5	А				
I _{DM}	Drain Current-Single Pulsed	10	A				
PD	Total Dissipation @T _c =25℃	35	W				
Tj	Max. Operating Junction Temperature	150	°C				
T _{stg}	Storage Temperature	-55~150	°C				

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	3.57	°C /W
Rth(ch-a)	Rth(ch-a) Channel-to-ambient thermal resistance		°C /W

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ELECTRICAL CHARACTERISTICS

$T_{C}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 10mA	650			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} = 10V; I _D =1.0mA	2.4		4.4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =1.3A		2300	2510	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} =0V			±1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =650V; V _{GS} = 0V			10	μA
VSDF	Diode forward voltage	I _{DR} =2.5A, V _{GS} = 0 V			1.7	V

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